

### Features

- Single-Supply Operation from +2.1V ~ +5.5V
- Rail-to-Rail Input / Output
- Gain-Bandwidth Product: 6MHz (Typ.)
- Low Input Bias Current: 1pA (Typ.)
- Low Offset Voltage: 3.5mV (Max.)
- Quiescent Current: 470µA per Amplifier (Typ.)
- Operating Temperature: -40°C ~ +125°C

### **General Description**

• Small Package:

ASOP8631 Available in SOT23-5, SOP-8 and SC70-5 Packages ASOP8632 Available in SOP-8 and MSOP-8 Packages ASOP8634 Available in SOP-14 and TSSOP-14 Packages

The ASOP863X have a high gain-bandwidth product of 6MHz, a slew rate of  $4.2V/\mu s$ , and a quiescent current of  $470 \mu A$  peramplifier at 5V. The ASOP863X are designed to provide optimal performance in low voltage and low noise systems. They provide rail-to-rail output swing into heavy loads. The input common mode voltage range includes ground, and the maximum input offset voltage is 3.5mV for ASOP863X. They are specified over the extended industrial temperature range ( $-40^{\circ}C$  to  $+125^{\circ}C$ ). The operating range is from 2.1V to 5.5V. The ASOP8631 single is available in Green SC70-5, SOT23-5 and SOP-8 packages. The ASOP8632 dual is available in Green SOP-8 and MSOP-8 packages. The ASOP8634 Quad is available in Green SOP-14 and TSSOP-14 packages.

# Applications

- Sensors
- Active Filters
- Cellular and Cordless Phones
- Laptops and PDAs

### **Pin Configuration**

- Audio
- Handheld Test Equipment
- Battery-Powered Instrumentation
- A/D Converters

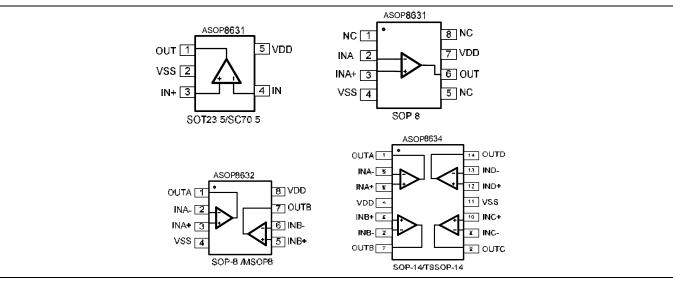


Figure 1. Pin Assignment Diagram



### **Absolute Maximum Ratings**

Condition	Min	Max		
Power Supply Voltage (V <sub>DD</sub> to Vss)	-0.5V	+7.5V		
Analog Input Voltage (IN+ or IN-)	Vss-0.5V	V <sub>DD</sub> +0.5V		
PDB Input Voltage	Vss-0.5V	+7V		
Operating Temperature Range	-40°C	+125°C		
Junction Temperature	+16	0°C		
Storage Temperature Range	-55°C	+150°C		
Lead Temperature (soldering, 10sec)	+260°C			
Package Thermal Resistance (TA=+25°C)				
SOP-8, θ <sub>JA</sub>	125°	C/W		
MSOP-8, θ <sub>JA</sub>	216°	C/W		
SOT23-5, θ <sub>JA</sub>	190°	C/W		
SOT23-6, θ <sub>JA</sub>	190°	190°C/W		
SC70-5, θ <sub>JA</sub>	333°C/W			
ESD Susceptibility				
НВМ	8KV			
MM	400V			

**Note:** Stress greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.



# **Electrical Characteristics**

(At Vs=5V, T\_A = +25  $^\circ \! \rm C$  , V\_{CM} = V\_S/2, R\_L = 600  $^\Omega$  , unless otherwise noted.)

				ļ	ASOP8631/2	/4		
		ТҮР	MIN/MAX OVER TEMPERATURE					
PARAMETER	CONDITIONS	10		0℃ to	-40°C	-40 ℃ to		MIN /
		+25℃	+25℃	70°C	to 85℃	125°C	UNITS	МАХ
INPUT CHARACTERISTICS	·	•						
Input Offset Voltage (V <sub>OS</sub> )		0.8	3.5	3.9	4.3	4.6	mV	MAX
Input Bias Current (I <sub>B</sub> )		1					pА	TYP
Input Offset Current (I <sub>OS</sub> )		1					pА	TYP
Input Common Mode Voltage Range (V <sub>CM</sub> )	V <sub>S</sub> = 5.5V	-0.1 to					V	TYP
		+5.6						
Common Mode Rejection Ratio (CMRR)	$V_{\rm S}$ = 5.5V, $V_{\rm CM}$ = -0.1V to 4V	90	73	70	70	65	dB	MIN
	$V_{\rm S}$ = 5.5V, $V_{\rm CM}$ = -0.1V to 5.6V	83					dB	MIN
Open-Loop Voltage Gain (A <sub>OL</sub> )	$R_L = 600\Omega, V_O = 0.15V \text{ to } 4.85V$	97	90	87	86	79	dB	MIN
	$R_L$ = 10k $\Omega$ , $V_O$ = 0.05V to 4.95V	108					dB	MIN
Input Offset Voltage Drift ( $\Delta V_{OS} / \Delta_T$ )		2.4					μ <b>V</b> /℃	TYP
OUTPUT CHARACTERISTICS	·	•						
Output Voltage Swing from Rail	R <sub>L</sub> = 600Ω	0.1					V	TYP
	$R_L = 10k\Omega$	0.015					V	TYP
Output Current (I <sub>OUT</sub> )		53	49	45	40	35	mA	MIN
Closed-Loop Output Impedance	f = 200kHz, G = 1	3					Ω	TYP
POWER-DOWN DISABLE	·	•		•		•	•	
Turn-On Time		4					μs	TYP
Turn-Off Time		1.2					μs	TYP
POWER SUPPLY	·	•		•		•	•	
Operating Voltage Range			2.1	2.1	2.1	2.1	V	MIN
			5.5	5.5	5.5	5.5	V	MAX
Power Supply Rejection Ratio (PSRR)	V <sub>S</sub> = +2.5V to +5.5V							
	$V_{CM} = (-V_S) + 0.5V$	91	74	72	72	68	dB	MIN
Quiescent Current/Amplifier ( $I_Q$ )	I <sub>OUT</sub> = 0	470	650	727	750	815	μA	MAX



## **Electrical Characteristics**

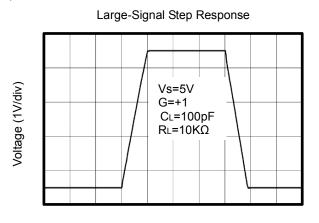
(At Vs=5V, T\_A = +25  $^\circ C$  , V\_{CM} = V\_S/2, R\_L = 600  $^\circ \Omega$  , unless otherwise noted.)

			ASOP8631/2/4 P MIN/MAX OVER TEMPERATURE						
PARAMETER	CONDITIONS	TYP							
PARAMETER	CONDITIONS	1.05%		0°C to	-40℃ to	-40℃to		MIN /	
		<b>+25℃</b>	<b>+25℃</b>	70°C	85°C	125℃	UNITS	MAX	
DYNAMIC PERFORMANCE								•	
Gain-Bandwidth Product (GBP)	$R_L = 10k\Omega, C_L = 100pF$	6					MHz	TYP	
Phase Margin ( $\phi_0$ )	$R_L$ = 10k $\Omega$ , $C_L$ = 100pF	53					Degrees	TYP	
Full Power Bandwidth (BWP)	${<}1\%$ distortion, RL = 600 $\Omega$	250					kHz	TYP	
Slew Rate (SR)	G = +1, 2V Step, $R_L$ = 10k $\Omega$	4.2					V/µs	TYP	
Settling Time to 0.1% $(t_s)$	G = +1, 2V Step, $R_L$ = 600 $\Omega$	0.4					μs	TYP	
Overload Recovery Time	$V_{IN} \cdot Gain = VS, R_L = 600\Omega$	2.5					μs	TYP	
NOISE PERFORMANCE									
Voltage Noise Density (e <sub>n</sub> )	f = 1kHz	13					$nV/\sqrt{Hz}$	TYP	
	f = 10kHz	9.5					$nV/\sqrt{Hz}$	TYP	

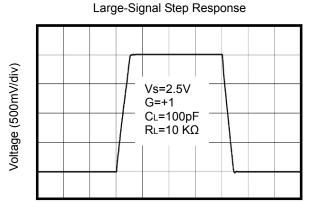


### **Typical Performance characteristics**

(At Vs=5V, T<sub>A</sub> = +25 $^{\circ}$ C, V<sub>CM</sub> = Vs/2, R<sub>L</sub> = 600 $\Omega$ , unless otherwise noted.)

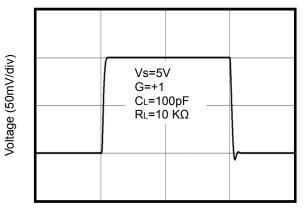


Time (1µs/div)

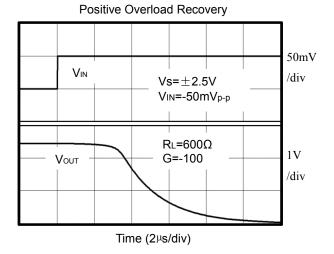


Time (1µs/div)

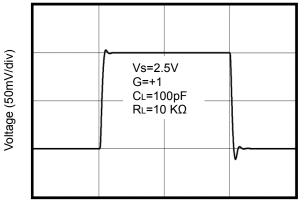
Small-Signal Step Response



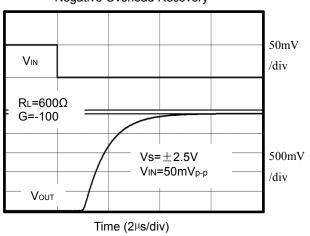
Time (1µs/div)

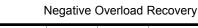


Small-Signal Step Response



Time (1µs/div)







### **Typical Performance characteristics**

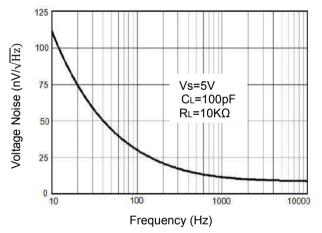
Output Voltage Swing vs.Output Current

(At Vs=5V, T<sub>A</sub> = +25  $^{\circ}$ C, V<sub>CM</sub> = Vs/2, R<sub>L</sub> = 600 $\Omega$ , unless otherwise noted.)

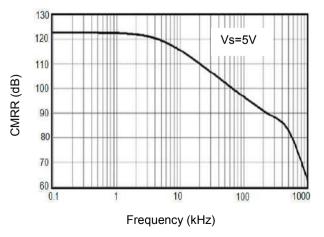
5 Sourcing Current Output Voltage (V) 3 **-50°**℃ **135**℃ **25℃** Vs=5V 2 0 Sinking Current -1 20 40 60 80 0

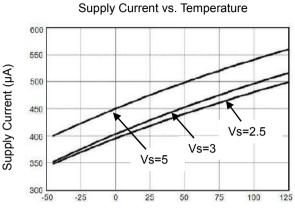
Output Current(mA)

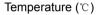


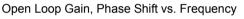


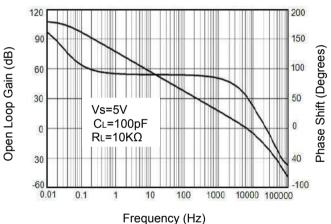


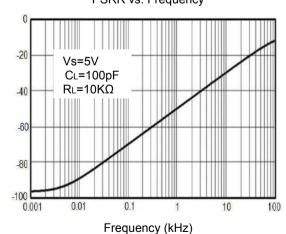












#### PSRR vs. Frequency

PSRR (dB)



### **Application Note**

#### Size

ASOP863X series op amps are unity-gain stable and suitable for a wide range of general-purpose applications. The small footprints of the ASOP863X series packages save space on printed circuit boards and enable the design of smaller electronic products.

#### **Power Supply Bypassing and Board Layout**

ASOP863X series operates from a single 2.1V to 5.5V supply or dual  $\pm 1.05V$  to  $\pm 2.75V$  supplies. For best performance, a 0.1µF ceramic capacitor should be placed close to the V<sub>DD</sub> pin in single supply operation. For dual supply operation, both V<sub>DD</sub> and V<sub>SS</sub> supplies should be bypassed to ground with separate 0.1µF ceramic capacitors.

#### **Low Supply Current**

The low supply current (typical 470uA per channel) of ASOP863X series will help to maximize battery life. They are ideal for battery powered systems

#### **Operating Voltage**

ASOP863X series operate under wide input supply voltage (2.1V to 5.5V). In addition, all temperature specifications apply from -40 °C to +125 °C. Most behavior remains unchanged throughout the full operating voltage range. These guarantees ensure

operation throughout the single Li-Ion battery lifetime

#### **Rail-to-Rail Input**

The input common-mode range of ASOP863X series extends 100mV beyond the supply rails ( $V_{SS}$ -0.1V to  $V_{DD}$ +0.1V). This is achieved by using complementary input stage. For normal operation, inputs should be limited to this range.

#### **Rail-to-Rail Output**

Rail-to-Rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating in low supply voltages. The output voltage of ASOP863X series can typically swing to less than 2mV from supply rail in light resistive loads (>100k $\Omega$ ), and 60mV of supply rail in moderate resistive loads (10k $\Omega$ ).

#### **Capacitive Load Tolerance**

The ASOP863X family is optimized for bandwidth and speed, not for driving capacitive loads. Output capacitance will create a pole in the amplifier's feedback path, leading to excessive peaking and potential oscillation. If dealing with load capacitance is a requirement of the application, the two strategies to consider are (1) using a small resistor in series with the amplifier's output and the load capacitance and (2) reducing the bandwidth of the amplifier's feedback loop by increasing the overall noise gain. Figure 2. shows a unity gain follower using the series resistor strategy. The resistor isolates the output from the capacitance and, more importantly, creates a zero in the feedback path that compensates for the pole created by the output capacitance.

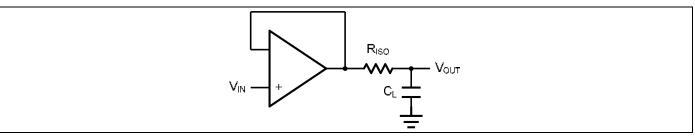


Figure 2. Indirectly Driving a Capacitive Load Using Isolation Resistor

The bigger the  $R_{ISO}$  resistor value, the more stable  $V_{OUT}$  will be. However, if there is a resistive load  $R_L$  in parallel with the capacitive load, a voltage divider (proportional to  $R_{ISO}/R_L$ ) is formed, this will result in a gain error.

The circuit in Figure 3 is an improvement to the one in Figure 2. R<sub>F</sub> provides the DC accuracy by feed-forward the V<sub>IN</sub> to R<sub>L</sub>. C<sub>F</sub>



and  $R_{ISO}$  serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving the phase margin in the overall feedback loop. Capacitive drive can be increased by increasing the value of  $C_{F}$ . This in turn will slow down the pulse response.

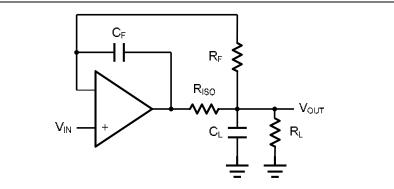


Figure 3. Indirectly Driving a Capacitive Load with DC Accuracy



# **Typical Application Circuits**

#### **Differential amplifier**

The differential amplifier allows the subtraction of two input voltages or cancellation of a signal common the two inputs. It is useful as a computational amplifier in making a differential to single-end conversion or in rejecting a common mode signal. Figure 4. shown the differential amplifier using ASOP863X.

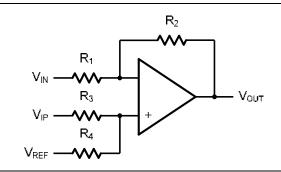


Figure 4. Differential Amplifier

$$V_{\text{OUT}} = \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_4}{R_1} V_{\text{IN}} - \frac{R_2}{R_1} V_{\text{IP}} + \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_3}{R_1} V_{\text{REF}}$$

If the resistor ratios are equal (i.e.  $R_1=R_3$  and  $R_2=R_4$ ), then

$$V_{\text{OUT}} = \frac{R_2}{R_1} (V_{\text{IP}} - V_{\text{IN}}) + V_{\text{REF}}$$

#### **Low Pass Active Filter**

The low pass active filter is shown in Figure 5. The DC gain is defined by  $-R_2/R_1$ . The filter has a -20dB/decade roll-off after its corner frequency  $f_c=1/(2\pi R_3C_1)$ .

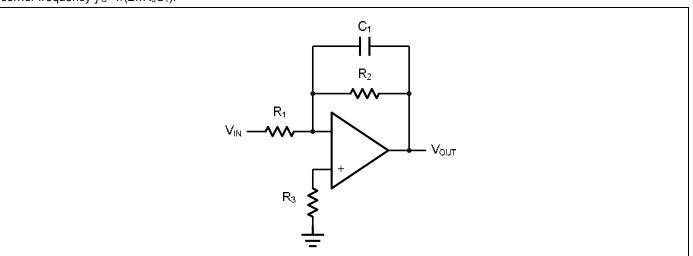


Figure 5. Low Pass Active Filter



#### **Instrumentation Amplifier**

The triple ASOP863X can be used to build a three-op-amp instrumentation amplifier as shown in Figure 6. The amplifier in Figure 6 is a high input impedance differential amplifier with gain of  $R_2/R_1$ . The two differential voltage followers assure the high input impedance of the amplifier.

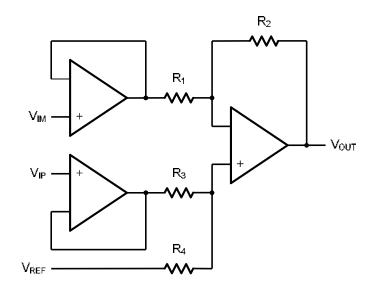
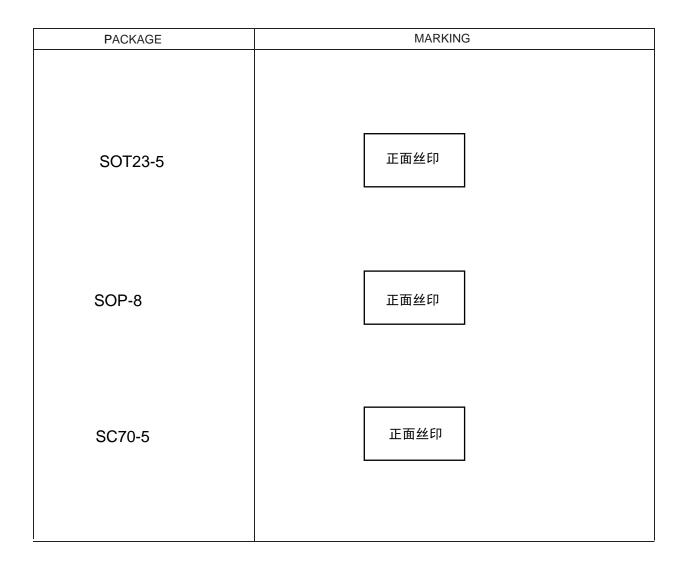


Figure 6. Instrument Amplifier



# **Ordering and Marking Information**

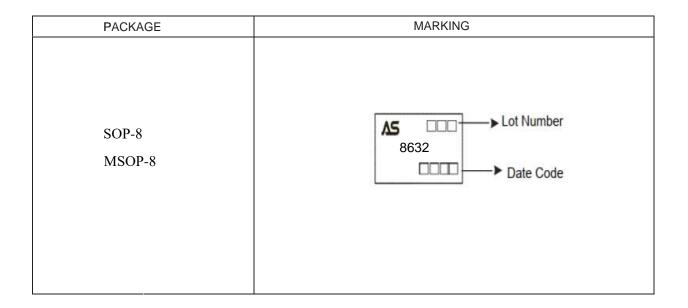
Device	Channel	Marking	Package	Packaging	Quantity
ASOP8631ZD-R	Singel	正面丝印	SOT23-5	Tape&Reel	3000/Reel
ASOP8631S-R	Singel	正面丝印	SOP-8	Tape&Reel	4000/Reel
ASOP8631CD-R	Singel	正面丝印	SC70-5	Tape&Reel	3000/Reel





# **Ordering and Marking Information**

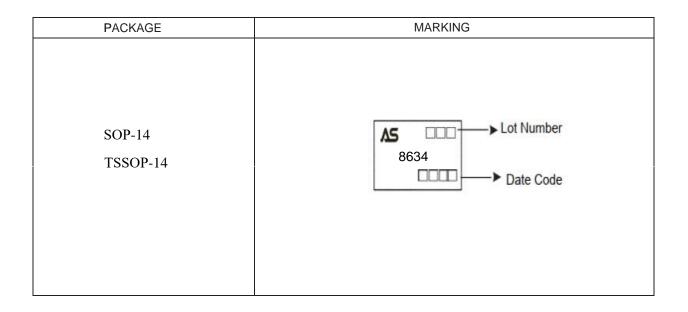
Device	Channel	Marking	Package	Packaging	Quantity
ASOP8632S-R	Dual	8632	SOP-8	Tape&Reel	4000/Reel
ASOP8632MS-R	Dual	8632	MSOP-8	Tape&Reel	3000/Reel





# **Ordering and Marking Information**

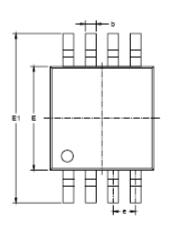
Device	Channel	Marking	Package	Packaging	Quantity
ASOP8634SA-R	Quad	8634	SOP-14	Tape&Reel	2500/Reel
ASOP8634ST-R	Quad	8634	TSSOP-14	Tape&Reel	3000/Reel



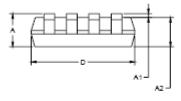


# **Package Information**

MSOP-8



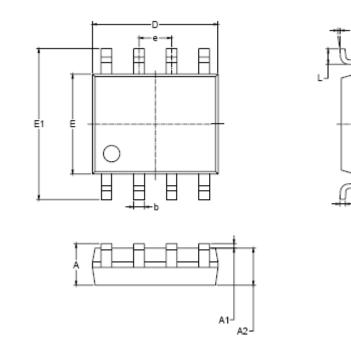




Symbol	Dimer In Milli	nsions meters	Dimensions In Inches		
	MIN	MAX	MIN	MAX	
A	0.820	1.100	0.032	0.043	
A1	0.020	0.150	0.001	0.006	
A2	0.750	0.950	0.030	0.037	
b	0.250	0.380	0.010	0.015	
с	0.090	0.230	0.004	0.009	
D	2.900	3.100	0.114	0.122	
E	2.900	3.100	0.114	0.122	
E1	4.750	5.050	0.187	0.199	
e	0.650 BSC		0.026	BSC	
L	0.400	0.800	0.016	0.031	
θ	0°	6°	0°	6°	



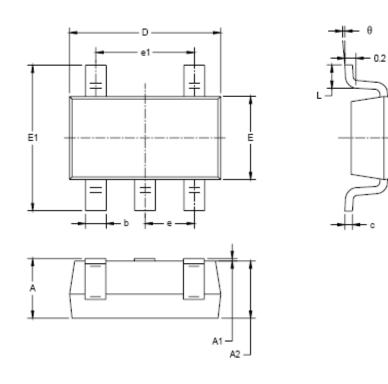
#### SOP-8



Symbol		nsions meters	Dimensions In Inches		
,	MIN	MAX	MIN	MAX	
А	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
с	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
e	1.27	1.27 BSC		BSC	
L	0.400	1.270	0.016	0.050	
e	0°	8°	0°	8°	



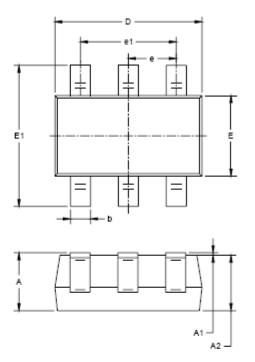
#### SOT23-5

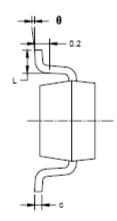


Symbol		isions imeters	Dimensions In Inches		
-,	MIN	MAX	MIN	MAX	
A	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
с	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
e	0.950	BSC	0.037	BSC	
e1	1.900	1.900 BSC		BSC	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	



#### SOT23-6

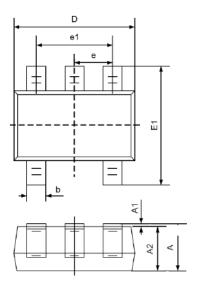


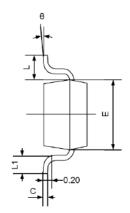


Symbol		nsions meters	Dimensions In Inches		
	MIN	MAX	MIN	MAX	
A	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
с	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
E	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
e	0.950	BSC	0.037 BSC		
e1	1.900 BSC		0.075	BSC	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	



#### SC70-5





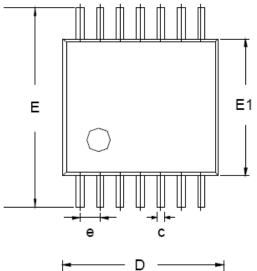
	Dimens	sions	Dimensions		
Symbol	In Milli	meters	In Inch	es	
	Min	Мах	Min	Max	
А	0.900	1.100	0.035	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.000	0.035	0.039	
b	0.150	0.350	0.006	0.014	
С	0.080	0.150	0.003	0.006	
D	2.000	2.200	0.079	0.087	
E	1.150	1.350	0.045	0.053	
E1	2.150	2.450	0.085	0.096	
e	0.650T	YP	0.026T	ΥP	
e1	1.200	1.400	0.047	0.055	
L	0.525R	0.525REF		EF	
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	

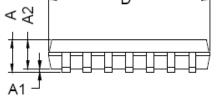


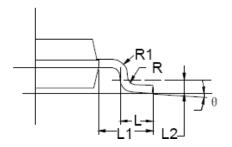
# ASOP8631/8632/8634

6MHZ CMOS Rail-to-Rail IO Opamps

#### **TSSOP-14**



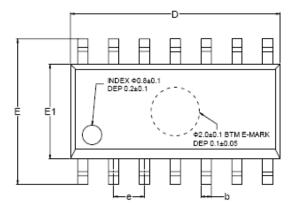


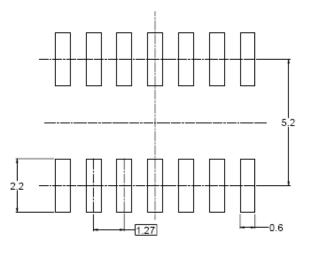


		Dimensions					
Symbol		In Millimeters					
oyinibor	MIN	ТҮР	MAX				
А	-	-	1.20				
A1	0.05	-	0.15				
A2	0.90	1.00	1.05				
b	0.20	-	0.28				
с	0.10	-	0.19				
D	4.86	4.96	5.06				
E	6.20	6.40	6.60				
E1	4.30	4.40	4.50				
е		0.65 BSC					
L	0.45	0.60	0.75				
L1		1.00 REF					
L2		0.25 BSC					
R	0.09	-	-				
θ	0°	-	8°				

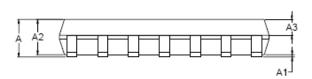


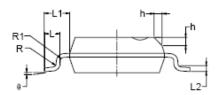
#### SOP-14





RECOMMENDED LAND PATTERN (Unit: mm)





Symbol	Dimensions In Millimeters			Dimensions In Inches		
	MIN	MOD	MAX	MIN	MOD	MAX
A	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.004		0.010
A2	1.25		1.65	0.049		0.065
A3	0.55		0.75	0.022		0.030
b	0.36		0.49	0.014		0.019
D	8.53		8.73	0.336		0.344
E	5.80		6.20	0.228		0.244
E1	3.80		4.00	0.150		0.157
e	1.27 BSC			0.050 BSC		
L	0.45		0.80	0.018		0.032
L1	1.04 REF			0.040 REF		
L2	0.25 BSC			0.01 BSC		
R	0.07			0.003		
R1	0.07			0.003		
h	0.30		0.50	0.012		0.020
θ	0°		8°	0°		8°



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